

Middle Power Class-D Speaker Amplifiers

Analog Input / Single End Output Class-D Speaker Amplifier

BD5445EFV



No.11075ECT16

Overview

BD5445EFV is a Analog input type Class D Speaker Amplifier designed for Flat-panel TVs in particular for space-saving and low-power consumption, delivers an output power of 17W+17W. This IC employs state-of-the-art Bipolar, CMOS, and DMOS (BCD) process technology that eliminates turn-on resistance in the output power stage and internal loss due to line resistances up to an ultimate level. With this technology, the IC can achieve high efficiency of 91% (10W+10W output with 8Ω load).In addition, the IC is packaged in a compact reverse heat radiation type power package to achieve low power consumption and low heat generation and eliminates necessity of external heat-sink up to a total output power of 34W. This product satisfies both needs for drastic downsizing, low-profile structures and powerful, high-quality playback of sound system.

Features

- 17W stereo single-ended outputs 34W mono bridge-tied-load output
- 2) Wide supply voltage (From 10V to 27V)
- 3) Four selectable gain (14, 20, 26, 32dB)
- 4) Master / Slave function
- 5) Soft-start and Soft-mute
- 6) Low noise, Low distortion
- 7) Various protection functions (High temperature, Output short, Under voltage)
- 8) Small power package (HTSSOP-B28)

Applications

Flat Panel TVs (LCD, Plasma), Home Audio, Desktop PC, Amusement equipments, Electronic Music equipments, etc.

●Absolute maximum ratings (Ta=25°C)

Item	Symbol	Limit	Unit	Conditions		
Supply voltage	Vcc	30	V	Pin 1, 15, 16, 27, 28	×1 >	※ 2
		1.45	W			Ж3
Power dissipation	Pd	3.30	W			₩4
		4.70	W			Ж5
Input voltage for signal	V _{IN}	-0.3 ~ 5.3	V	Pin 4, 5		※ 1
Input voltage for control	V _{CONT}	-0.3 ~ Vcc + 0.3	V	Pin 2, 3, 10, 11, 13	3	※ 1
Input voltage for clock	Vosc	-0.3 ~ 5.3	V	Pin 12	;	※ 1
Operating temperature range	Topr	-25 ~ +85	°C			
Storage temperature range	Tstg	-55 ~ +150	°C			
Maximum junction temperature	Tjmax	+150	°C			

**1 The voltage that can be applied, based on Gnd(Pin6, 20, 21, 22, 23)
**2 Do not, however exceed Pd and Tjmax=150°C.
**3 70mm × 70mm × 1.6mm, FR4, 1-layer glass epoxy board (Copper on bottom layer 0%) Derating in done at 11.6mW/°C for operating above Ta=25°C.
**4 70mm × 70mm × 1.6mm, FR4, 2-layer glass epoxy board (Copper on bottom layer 100%) Derating in done at 26.4mW/°C for operating above Ta=25°C. There are thermal via on the board.
*5 70mm × 70mm × 1.6mm, FR4, 4-layer glass epoxy board (Copper on bottom layer 100%) Derating in done at 37.6mW/°C for operating above Ta=25°C. There are thermal via on the board.

●Operating conditions (Ta=25°C)

Item	Symbol	Limit	Unit	Conditions
Supply voltage	Vcc	10 ~ 27	V	Pin 1, 15, 16, 27, 28
Minimum load impedance	R_L	3.6	Ω	*6

Do not, however exceed Pd. No radiation-proof design <u>Ж</u>6

Х

●Electrical characteristics (Unless otherwise specified Ta=25°C, Vcc=24V, f=1kHz, R_L=8Ω, Po=1W, Gain=20dB, PDX=24V. MUTEX=24V. MS=0V. Single-ended outputs)

Item	Symbol		Limit	1	Unit	Conditions	
item	Symbol	Min	Тур	Max	Offic	Conditions	
Whole circuit	1	I	I	I	ſ		
Circuit current 1	I _{CC1}	-	25	50	mA	Pin 1, 15, 16, 27, 28 No load, No signal	
Circuit current 2 (Power down mode)	I _{CC2}	-	2	4	mA	Pin 1, 15, 16, 27, 28 PDX=0V,MUTEX=0V, No loa signal	d, Nc
Control circuit		1	1	1			
High level input voltage for control	V _{IH}	2.5	-	24	V	Pin 2, 3, 10, 11, 13	
Low level input voltage for control	V _{IL}	0	-	0.8	V	Pin 2, 3, 10, 11, 13	
High level input voltage for clock	V _{IHC}	2.5	-	5	V	Pin 12	
Low level input voltage for clock	V _{ILC}	0	-	0.8	V	Pin 12	
Audio circuit		1	1	1	I		
NA	P ₀₁	-	10	-	14/	R _L =8Ω, THD+n=10%	Ж7
Momentary maximum output powe	P _{O2}	-	17	-	W	R _L =4Ω, THD+n=10%	Ж7
	G _{V0}	12	14	16	40	Gain1=0V, Gain0=0V	Ж7
Voltago gain	G _{V1}	18	20	22		Gain1=0V, Gain0=24V	Ж7
Voltage gain	G _{V2}	24	26	28	dB	Gain1=24V, Gain0=0V	Ж7
	G _{V3}	30	32	34		Gain1=24V, Gain0=24V	Х
Total harmonic distortion	THD	-	0.05	-	%	BW=20~20kHz	*
Crosstalk	СТ	60	75	-	dB	Rg=0Ω, BW=IHF-A	*
Output noise voltage	V _{NO}	-	80	160	µVrms	Rg=0Ω, BW=IHF-A	*
Residual noise voltage (Power down mode)	V _{NOR}	-	1	10	μVrms	PDX=0V, MUTEX=0V Rg=0Ω, BW=IHF-A	*
Mute attenuation	G _{∨M}	80	94	-	dB	MUTEX=0V, BW= IHF-A	*
Power supply rejection ratio	PSRR	-	60	-	dB	Vripple=1Vrms, BW= IHF-A Rg=0Ω, fripple=100Hz	×7
Internal oscillation frequency	Fosc	480	600	720	kHz	Pin 12, MS=0V	*
External clock frequency	F _{EXT}	480	-	720	kHz	Pin 12, MS=24V	*

%7 These items show the typical performance of device and depend on board layout, parts, power supply. The standard value is in mounting device and parts on surface of ROHM's board directly.

●Typical Characteristics Data (SE×2ch) Measured on ROHM's evaluation board.



Fig. 1 Power supply voltage-Current consumption





Fig.5 Output power-Crosstalk



Fig. 2 Power supply voltage-Current consumption





Fig.6 Frequency-Crosstalk

●Typical Characteristics Data (SE×2ch) Measured on ROHM's evaluation board.



Fig.7 Frequency–Voltage gain



Fig.8 FFT of Output Noise Voltage



Fig.9 Waveform when releasing Power-down



Fig.11 Waveform when releasing Soft-mute



Fig.10 Waveform when activating Power-down



Fig.12 Waveform when activating Soft-mute

●Typical Characteristics Data (SE×2ch) Measured on ROHM's evaluation board.





Fig.15 Total output power-Current consumption ($R_L=8\Omega$)













Typical Characteristic Data (SE × 2ch) Measured on ROHM's evaluation board. Dotted lines of the graphs indicate continuous output power by installing additional heat sinks.



Fig.19 Power supply voltage – Output power ($R_L=4\Omega$)



Fig.21 Total output power – Current consumption (R_L =4 Ω)



Fig.20 Output power-Efficiency (RL=4 Ω)

100



100





Fig.23 Frequency-THD+n





Fig.27 Output power-Efficiency ($R_L=8\Omega$)

Fig.26 Power supply voltage – Output power ($R_L=8\Omega$)

Vcc (V)

5

0

8 10 12 14 16 18 20 22 24 26 28 30 ●Typical Characteristics Data (BTL) Measured on ROHM's evaluation board.



Fig.28 Total output power – Current consumption ($R_L=8\Omega$)

Pin configuration and Block diagram



•Pin function explanation (Provided pin voltages are typ. values)

Pin function explanation (Provided pin voltages are typ. values)				
Pin No.	Pin name VCCA	Pin voltage Vcc	Pin explanation Power supply pin for Analog signal	Internal equivalence circuit
1	VCCA	VCC	Power supply pin for Analog signal	
2 3	GAIN0 GAIN1		Gain control pin	
4 5	IN1 IN2	2.5V	ch1 Analog signal input pin ch2 Analog signal input pin Input audio signal via a capacitor.	
6	GNDA	0V	Gnd pin for Analog signal	
7	FILA	2.5V	Bias pin for Analog signal	
			Please connect the capacitor.	
8	FILP	2~4V	Bias pin for PWM signal	
			Please connect the capacitor.	
9	ROSC	2.5V	Internal PWM sampling clock frequency setting pin Please connect the resister setting Master mode. Please connect the capacitor setting Slave mode.	30 Ω 40K Ω 9 Slave mode Master mode
10	PDX	_	Power down control pin H: Power down OFF L: Power down ON	

Pin No.	Pin name	Pin voltage	Pin explanation	Internal equivalence circuit
11	MUTEX	_	Speaker output mute control pin H: Mute OFF L: Mute ON	
12	OSC	_	PWM sampling clock input and output pin When using 2 or more ICs, connect to these pins.	12 Master mode =ON
13	MS	_	Master mode and Slave mode control pin H: Slave mode L: Master mode	
14	REG_G	5.5V	Internal power supply pin for Gate driver Please connect the capacitor.	
15 16 17 18	VCCP2 OUT2	Vcc 0V~Vcc	Power supply pin for ch2 PWM signal Output pin of ch2 PWM Please connect to Output LPF.	
19	BSP2	5V	Please connect the capacitor.	
20 21	GNDP2	0V	Gnd pin for ch2 PWM signal	20,21

Pin No.	Pin name	Pin voltage	Pin explanation	Internal equivalence circuit
22 23	GNDP1	0V	Gnd pin for ch1 PWM signal	27.28
24	BSP1	5V	Boot-strap pin of ch1 Please connect the capacitor.	
25 26	OUT1	0V~Vcc	Output pin of ch1 PWM Please connect to Output LPF.	25,26
27 28	VCCP1	Vcc	Power supply pin for ch1 PWM signal	

•Audio input circuit (pin4 and pin5)

Connect the audio input pin with a prior-stage circuit via coupling capacitors C4 and C5. Because C4, C5 and input impedance R4, R5 of the IC circuit compose the primary HPF, the values determine an input low-band cutoff frequency. Input cutoff frequencies are calculated by the following formulas:

$$f_{C} = \frac{1}{2\pi R4 \cdot C4} [Hz]$$
 $f_{C} = \frac{1}{2\pi R5 \cdot C5} [Hz]$

An excessively high capacitance of an input coupling capacitor results in a longer period required for stabilizing a power input pin voltage after turning on the power supply. Note that placing the MUTEX pin (pin11) at "L" level (mute turned off) for avoidance of Pop-noise before stabilizing an input pin. R4 and R5 are changed by Gain setting.

GAIN1 (3pin)	GAIN0 (2pin)	R4,R5 input impedance(TYP.)	Amplifier Gain (SE)	Amplifier Gain (BTL)
L	L	40kΩ	14dB	20dB
L	Н	40k Ω	20dB	26dB
Н	L	26.7kΩ	26dB	32dB
Н	Н	16k Ω	32dB	38dB



Fig. 29 Coupling capacitors of audio input pins

Output LC Filter Circuit (Pins 17, 18, 25, and 26)

An output filter is required to eliminate radio-frequency components exceeding the audio-frequency region supplied to a load (speaker). Because this IC uses sampling clock between 480kHz and 720kHz in the output PWM signals, the high-frequency components must be appropriately removed.

This section takes an example of an LC type LPF, in which coil Lfil and capacitor Cfil compose a differential filter with an attenuation property of -12dB/oct. A large part of switching currents flow to capacitor Cfil, and only a small part of the currents flow to speaker RL. The following is a table for output LC filter constants.

Speaker	RL	$L_{fil}[\mu H]$	C _{fil1} [μF]	C _{fil2} [μF]
	4Ω	22	0.68	
SE output	6Ω	33	0.47	—
	8Ω	47	0.39	
	4Ω	15	0.22	1
BTL output	6Ω	22	0.15	0.68
	8Ω	33	0.1	0.47

In SE(single end) applications, the dc blocking capacitor (Cse) and speaker impedance compose the primary HPF. The cutoff frequency is determined by

$$f_{\rm C} = \frac{1}{2\pi C_{\rm SE} \cdot R_{\rm L}} [Hz]$$

The following table is Cse setting at cutoff frequency 20Hz, 40Hz, and 60Hz.

R	$C_{SE}[\mu F]$			
	fc=60Hz	fc=40Hz	fc=20Hz	
4 Ω	680	1000	2200	
6Ω	470	680	1500	
8Ω	330	470	1000	



Fig.30 SE filter configuration



Control pins function

①GAIN0, GAIN1 function

GAIN1 (Pin 3)	GAIN0 (Pin 2)	Amplifier Gain (SE)	Amplifier Gain (BTL)
L	L	14dB	20dB
L	Н	20dB	26dB
н	L	26dB	32dB
Н	Н	32dB	38dB

②MUTEX, PDX function

MUTEX (Pin 11)	PDX (Pin 10)	Speaker output	Power down	
L	L	HiZ_Low	ON	
L	Н	Mute	OFF	
Н	Н	Normal operation	OFF	
Н	L	Forbidden		

③MS function

MS (13pin)	Mode
L	Master mode
Н	Slave mode

%Please connect ROSC terminal (pin 9) to 22kohm resister for setting master mode.

%Please connect to the following filter, and input clock (duty = 50%) to OSC terminal (pin 12) for setting slave mode.

PWM Sampling frequency is sited from input clock. If input clock have noise (ex.Jitter), noise appear to Speaker output.



Fig.32 ROSC terminal filter circuit for setting slave mode.

% High level input voltage (Max.voltage) of tease control pin is equal to Vcc voltage. But absolute max.voltage of In0(pin4),ROSC(pin9),OSC(pin12) and REG_G(pin14) is 5.3V. Tease pins may break, when short next pins. If these pins short to Vcc, connecting through 10kΩ resister prevent IC from destruction.



Power supply start-up sequence



Power supply shut-down sequence



Power supply shut down, after PDX (Pin 10) change H→L. The IC has possibly to sound POP noise, if PDX (Pim10) keep H. Speaker's coupling capacitor (Fig30:Cse) don't discharge at this time. Pop-noise may sound when power supply start up at the next time.

Power supply start-up and shut-down sequence for single control

Short between PDX(Pin 10) and MUTEX(Pin 11), enable to control these pins at one time.



PDX (Pin 10) and MUTEX (Pin 11) set low at one time, while this IC is on normal mode, the IC don't operate soft-mute. If low frequency and high level signal input this time, the IC has possibility to sound POP-Noise. To avoid this POP-Noise configure the following circuit, because PDX (Pin10) enables to change low after MUTEX (Pin11) have changed. This sequence make less POP-Noise because the IC can operate soft-mute.



Control configuration for soft-mute operation by single control

About the protection function

Protection function		Detecting & Releasing condition	PWM Output
Output short	Detecting condition	Detecting current = 10A (TYP.)	HiZ_Low
protection	Releasing condition	Release from Vcc or Gnd short	Normal operation
High	Detecting condition	Chip temperature to be above 150°C (TYP.)	HiZ_Low
temperature protection	Releasing condition	Chip temperature to be below 125°C (TYP.)	Normal operation
Under voltage	Detecting condition	Power supply voltage to be below 8V (TYP.)	HiZ_Low
protection	Releasing condition	Power supply voltage to be above 9V (TYP.)	Normal operation

% All protection functions are restored automatically when the fault is removed.

1) Output short protection (Short to the power supply)

This IC has the output short protection circuit that stops the PWM output when the PWM output is short-circuited to the power supply due to abnormality.

Detecting condition – It will detect when PDX pin is set High and the current that flows in the PWM output pin becomes 10A(TYP.) or more. The PWM output instantaneously enters the state of HiZ-Low if detected, and IC does the latch.

Releasing method – This IC detect releasing from Vcc short every 220msec(TYP.). Normal operation is restored when releasing from Vcc short.



2) Output short protection (Short to Gnd)

This IC has the output short protection circuit that stops the PWM output when the PWM output is short-circuited to Gnd due to abnormality.

Detecting condition – It will detect when PDX pin is set High and the current that flows in the PWM output terminal becomes 10A(TYP.) or more. The PWM output instantaneously enters the state of HiZ-Low if detected, and IC does the latch.

Releasing method – This IC detect releasing from Gnd short every 220msec(TYP.). Normal operation is restored when releasing from Gnd short.



(※)Remark of output short protection

Circuit current changes suddenly, when IC detects output short protection. At this time IC may break, because supply voltage rise up by back electromotive force. Decoupling capacitors (VCCPI and VCCP2) should be placed as close to the IC as possible. (recommend $4.7 \,\mu$ F or more.)

3) High temperature protection

This IC has the high temperature protection circuit that prevents thermal reckless driving under an abnormal state for the temperature of the chip to exceed Tjmax=150°C.

Detecting condition - It will detect when PDX pin is set High and the temperature of the chip becomes 150°C(TYP.) or more. The speaker output is muted through a soft-mute when detected.

Releasing condition - It will release when PDX pin is set High and the temperature of the chip becomes 120°C(TYP.) or less. The speaker output is outputted through a soft-start when released.



4) Under voltage protection

This IC has the under voltage protection circuit that make speaker output mute once detecting extreme drop of the power supply voltage.

Detecting condition – It will detect when PDX pin is set High and the power supply voltage becomes lower than 8V. The speaker output is muted when detected.

Releasing condition – It will release when PDX pin is set High and the power supply voltage becomes more than 9V. The speaker output is outputted through a soft-start when released.



●Application Circuit Example (single-ended output ×2)



•BOM List (single-ended output $\times 2$)

Parts	Parts No.	Value	Company	Product No.	Rated Voltage	Tolerance	Size
IC	U1	-	ROHM	BD5444EFV	-	-	9.7mm×6.4mm
Inductor	L17, L25	47µH	ТОКО	A7503AY-470M	-	±20%	φ11mm×13.5mm
	R1	10Ω		MCR18EZHF10R0	1/4W	F(±1%)	3.2mm×1.6mm
Resistor	R9A	22kΩ	ROHM	MCR01MZPF2202	1/16W	F(±1%)	1.0mm×0.5mm
	R17,R25	15Ω		MCR18EZHF15R0	1/4W	F(±1%)	3.2mm×1.6mm
	C1	10µF		GRM32DF51H106ZA01	50V	Y5V (+80% / -20%)	3.2mm×2.5mm
	C19, C24	4.7uF		GRM21BB31C475KA87	16V	B(±10%)	2.0mm×1.2mm
Capacitor	C15A, C27A	4.7uF	MURATA	GRM31CF11H475ZA01	50V	F (+80% / -20%)	3.2mm×1.6mm
	C17A, C25A	0.39uF		GRM32MB11H394KA01	50V	B(±10%)	3.2mm×2.5mm
	C14	3.3µF		GRM188B31A335KE15	10V	B(±10%)	1.6mm×0.8mm
	C4, C5, C7	1µF		GRM185B30J105KE25	6.3V	B(±10%)	1.6mm×0.8mm
	C17B, C25B	330pF		GRM188B11H331KA01	50V	B(±10%)	1.6mm×0.8mm
Electrolytic Capacitor	C15B, C17C, C25C, C27B	470µF	Rubycon	35ZLH470M	35V	±20%	φ10mm×16mm
	C8	100uF		16ZLH100M	16V	±20%	φ5mm×11mm

(%1) Please change the following parts, when using RL=6 $\Omega\,$ speaker.

Inductor	L17, L25	33µH	ТОКО	A7503AY-330M	_	±20%	φ11mm×13.5mm
Resistor	R17,R25	10Ω	ROHM	MCR18EZHF10R0	1/4W	F(±1%)	3.2mm×1.6mm
	C17A, C25A	0.47µF	MURATA	GRM32MB11H474KA01	50V	B(±10%)	3.2mm×2.5mm
	C17B, C25B	680pF		GRM188B11H681KA01	50V	B(±10%)	1.6mm×0.8mm
Capacitor	C17C, C25C	680µF	Rubycon	35ZLH680M	35V	±20%	φ10mm×23mm

(%2) Please change the following parts, when using RL=4 $\Omega\,$ speaker.

Inductor	L17, L25	22µH	ТОКО	A7503AY-220M	-	±20%	φ11mm×13.5mm
Resistor	R17,R25	5.6Ω	ROHM	MCR18EZHFL5R60	1/4W	F(±1%)	3.2mm×1.6mm
	C17A, C25A	0.68µF	MURATA	GRM32NB11H684KA01	50V	B(±10%)	3.2mm×2.5mm
Canacitar	C17B, C25B	1000pF	NORATA	GRM188B11H102KA01	50V	B(±10%)	1.6mm×0.8mm
Capacitor	C17C, C25C	1000µF	Rubycon	35ZLH1000M	35V	±20%	φ12.5mm×20mm

Application Circuit Example (BTL output)



BOM List (BTL output)

Parts	Parts No.	Value	Company	Product No.	Rated Voltage	Tolerance	Size
IC	U1	-	ROHM	BD5444EFV	-	-	9.7mm×6.4mm
Inductor	L17, L25	33µH	ТОКО	A7503AY-330M	_	±20%	φ11mm×13.5mm
	R1	10Ω		MCR18EZHF10R0	1/4W	F(±1%)	3.2mm×1.6mm
Resistor	R9A	22kΩ	ROHM	MCR01MZPF2202	1/16W	F(±1%)	1.0mm×0.5mm
	R17,R25	15Ω		MCR18EZHF15R0	1/4W	F(±1%)	3.2mm×1.6mm
	C1	10µF		GRM32DF51H106ZA01	50V	Y5V (+80% / -20%)	3.2mm×2.5mm
	C19, C24	4.7uF		GRM21BB31C475KA87	16V	B(±10%)	2.0mm×1.2mm
Capacitor	C15A, C27A	4.7uF	MURATA	GRM31CF11H475ZA01	50V	F (+80% / -20%)	3.2mm×1.6mm
	C17A, C25A	0.1uF		GRM188B31H104KA92	50V	B(±10%)	1.6mm×0.8mm
	C17D	0.47uF		GRM32MB11H474LA01	50V	B(±20%)	3.2mm x 2.5mm
	C14	3.3µF		GRM188B31A335KE15	10V	B(±10%)	1.6mm×0.8mm
-	C4, C5, C7	1µF		GRM185B30J105KE25	6.3V	B(±10%)	1.6mm×0.8mm
-	C17B, C25B	330pF		GRM188B11H331KA01	50V	B(±10%)	1.6mm×0.8mm
Electrolytic	C15B, C27B	470µF	35ZLH470M	35V	±20%	φ10mm×16mm	
Capacitor	C8	100uF	Rubycon	16ZLH100M	16V	±20%	φ5mm×11mm

(%1) Please change the following parts, when using RL=6 $\Omega\,$ speaker.

Inductor	L17, L25	22µH	TOKO	A7503AY-220M		±20%	φ11mm×13.5mm
Resistor	R17,R25	10Ω	ROHM	MCR18EZHF10R0	1/4W	F(±1%)	3.2mm×1.6mm
	C17A, C25A	0.15µF		GRM21BB31H154MA88	50V	B(±20%)	2.0mm×1.2mm
Capacitor	C17B, C25B	680pF	MURATA	GRM188B11H681KA01	50V	B(±10%)	1.6mm×0.8mm
	C17D	0.68µF		GRM32NB11H684MA01	50V	B(±20%)	3.2mm×2.5mm

(%2) Please change the following parts, when using RL=4 Ω speaker.

Inductor	L17, L25	15µH	ТОКО	A7503AY-150M	-	±20%	φ11mm×13.5mm
Resistor	R17,R25	5.6Ω	ROHM	MCR18EZHFL5R60	1/4W	F(±1%)	3.2mm×1.6mm
	C17A, C25A	0.22µF		GRM21BB31H224MA88	50V	B(±20%)	2.0mm x 1.2mm
Capacitor	C17B, C25B	1000pF	MURATA	GRM188B11H102KA01	50V	B(±10%)	1.6mm×0.8mm
	C17D	1µF		GRM31MB31H105KA87	50V	B(±20%)	3.2mm×2.5mm

Application Circuit Example (2.1ch output)



●BOM List (2.1ch output)

Parts	Parts No.	Value	Company	Product No.	Rated Voltage	Tolerance	Size
Resistor	R9B	22kΩ	ROHM	MCR01MZPF2202	1/16W	F(±1%)	1.0mm×0.5mm
Capacitor	C9A	2200pF	MURATA	GRM155R61A222KA01	10V	X5R(±10%)	1.0mm × 0.5mm
Capacitor	C9B	220pF	NORATA	GRM1552C1E221JA01	25V	CH(±5%)	1.0mm × 0.5mm

(%) Parts are written used at "Slave mode" only. Please use same parts written P23 ~ P26.

Notes for use

1) Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as a fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.

2) Power supply lines

As return of current regenerated by back EMF of output coil happens, take steps such as putting capacitor between power supply and Gnd as a electric pathway for the regenerated current. Be sure that there is no problem with each property such as emptied capacity at lower temperature regarding electrolytic capacitor to decide capacity value. If the connected power supply does not have sufficient current absorption capacity, regenerative current will cause the voltage on the power supply line to rise, which combined with the product and its peripheral circuitry may exceed the absolute maximum ratings. It is recommended to implement a physical safety measure such as the insertion of a voltage clamp diode between the power supply and Gnd pins.

3) Gnd potential (Pin 6, 20, 21, 22, 23)

Ensure a minimum Gnd pin potential in all operating conditions.

4) Input terminal

The parasitic elements are formed in the LSI because of the voltage relation. The parasitic element operating causes the wrong operation and destruction. Therefore, please be careful so as not to operate the parasitic elements by impressing to input terminals lower voltage than Gnd. Please do not apply the voltage to the input terminal when the power-supply voltage is not impressed.

5) Setting of heat

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions. This IC exposes its frame of the backside of package. Note that this part is assumed to use after providing heat dissipation treatment to improve heat dissipation efficiency. Try to occupy as wide as possible with heat dissipation pattern not only on the board surface but also the backside.

Class D power amplifier is High efficiency and low heat generation by comparison with conventional Analog power amplifier. However, In case it is operated continuously by maximum output power, Power dissipation(Pdiss) may exceed package dissipation. Please consider about heat design that Power dissipation(Pdiss) does not exceed Package dissipation(Pd) in average power(Poav). (Tjmax :Maximum junction temperature=150°C, Ta :Peripheral temperature[°C], θja :Thermal resistance of package[°C/W], Poav:Average power[W], η:Efficiency)

Package dissipation: Pd (W) = $(Tjmax - Ta) \neq \theta ja$ Power dissipation: Pdiss(W) = Poav * $(1 \neq \eta - 1)$

6) Actions in strong magnetic field

Use caution when using the IC in the presence of a strong magnetic field as doing so may cause the IC to malfunction.

7) Thermal shutdown circuit

This product is provided with a built-in thermal shutdown circuit. When the thermal shutdown circuit operates, the output transistors are placed under open status. The thermal shutdown circuit is primarily intended to shut down the IC avoiding thermal runaway under abnormal conditions with a chip temperature exceeding Tjmax = 150°C.

8) Shorts between pins and misinstallation

When mounting the LSI on a board, pay adequate attention to orientation and placement discrepancies of the LSI. If it is misinstalled and the power is turned on, the LSI may be damaged. It also may be damaged if it is shorted by a foreign substance coming between pins of the LSI or between a pin and a power supply or a pin and a Gnd

9) Power supply on/off (Pin 1, 15, 16, 27, 28)

In case power supply is started up, PDX (Pin 10) and MUTEX (Pin 11) always should be set LOW, And in case power supply is shut down, it should be set LOW likewise. Then it is possible to eliminate pop noise when power supply is turned on/off. And also, all power supply terminals should start up and shut down together.

10) Precautions for Speaker-setting

If the impedance characteristics of the speakers at high-frequency range while increase rapidly, the IC might not have stable-operation in the resonance frequency range of the LC-filter. Therefore, consider adding damping-circuit, etc., depending on the impedance of the speaker.

Allowable Power Dissipation



Measuring instrument : TH-156 (Kuwano Electrical Instruments Co., Ltd.) Measuring conditions : Installation on ROHM's board Board size : 70mm×70mm×1.6mm (with thermal via on board) Material : FR4

• The board on exposed heat sink on the back of package are connected by soldering.

$\text{PCB}(\underline{1}: 1\text{-layer board}$	(back copper foil size: 0mm×0mm),	θja=86.2°C/W
PCB2 : 2-layer board	(back copper foil size: 70mm×70mm),	θja=37.8°C/W
PCB3 : 4-layer board	(back copper foil size: 70mm×70mm),	θja=26.6°C/W

BD5445EFV

Ordering part number



HTSSOP-B28



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